

# Near Threshold Resonant Processes in Plasmas

F. Robicheaux, S. Loch, M. Pindzola,  
C. Balance, J. van der Hyden

Auburn University

Support from DOE

Threshold resonances strongly contribute to  
recombination.

Accurate energy is wildly important.

## STORAGE RING MEASUREMENT OF THE C IV RECOMBINATION RATE COEFFICIENT

S. SCHIPPERS AND A. MÜLLER

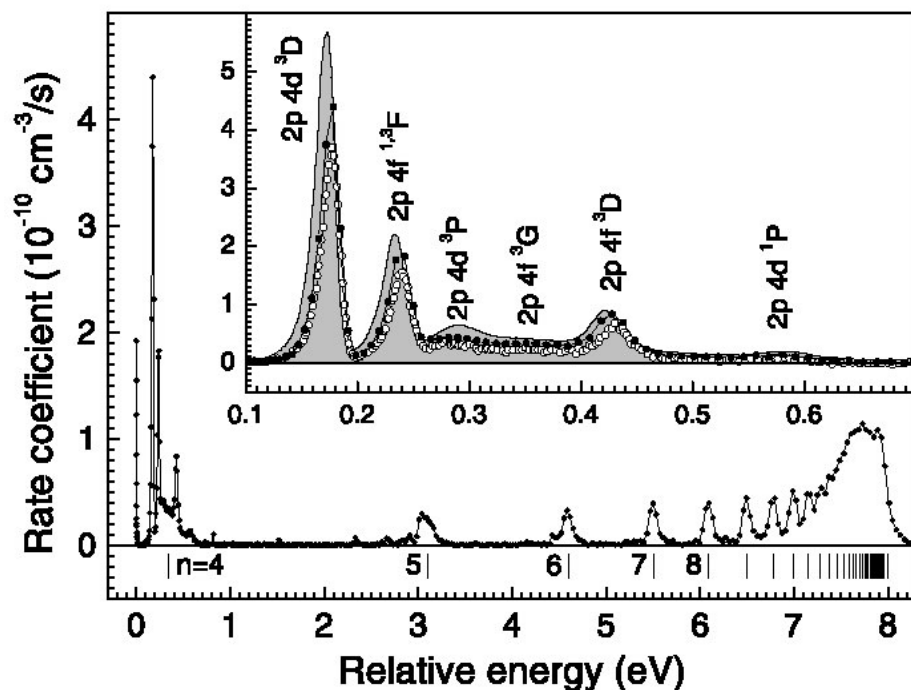
Institut für Kernphysik, Strahlenzentrum der Justus-Liebig-Universität, 35392 Giessen, Germany

AND

G. GWINNER, J. LINKEMANN, A. A. SAGHIRI, AND A. WOLF

Max-Planck-Institut für Kernphysik, 69117 Heidelberg, Germany; and Physikalisches Institut der Universität Heidelberg, 69120 Heidelberg, Germany

Received 2001 January 31; accepted 2001 March 19



Resonances of  $\text{C}^{2+}$  with  $2p4L$  character are within  $\sim 1/2$  eV of threshold

$0.1 \text{ eV} = 1160 \text{ K}$

Dielectronic recombination in cold plasmas!

# Thermal Rates: DR only

derived from  
experiment

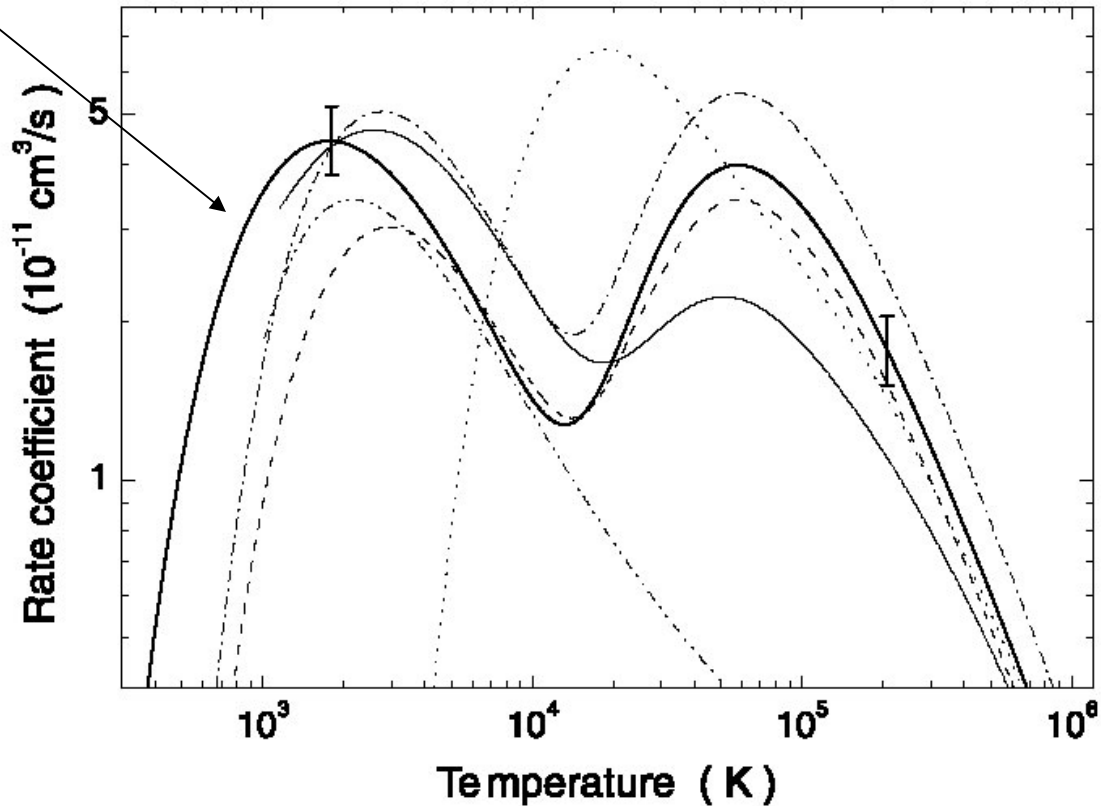


FIG. 6.—C IV  $\Delta n = 0$  DR rate coefficients in a plasma: this work (*thick solid line*; systematic uncertainty  $\pm 15\%$ ), McLaughlin & Hahn (1983; *dashed line*), Nussbaumer & Storey (1983; *dash-double-dotted line*), Romanik (1988; *dash-dotted line*), Safronova et al. (1997; *thin solid line*), and Mazzotta et al. (1998; *dotted line*).

# Thermal Rates: DR+RR

derived from  
experiment

RR and DR  
have same  
rate  $\sim 800$  K

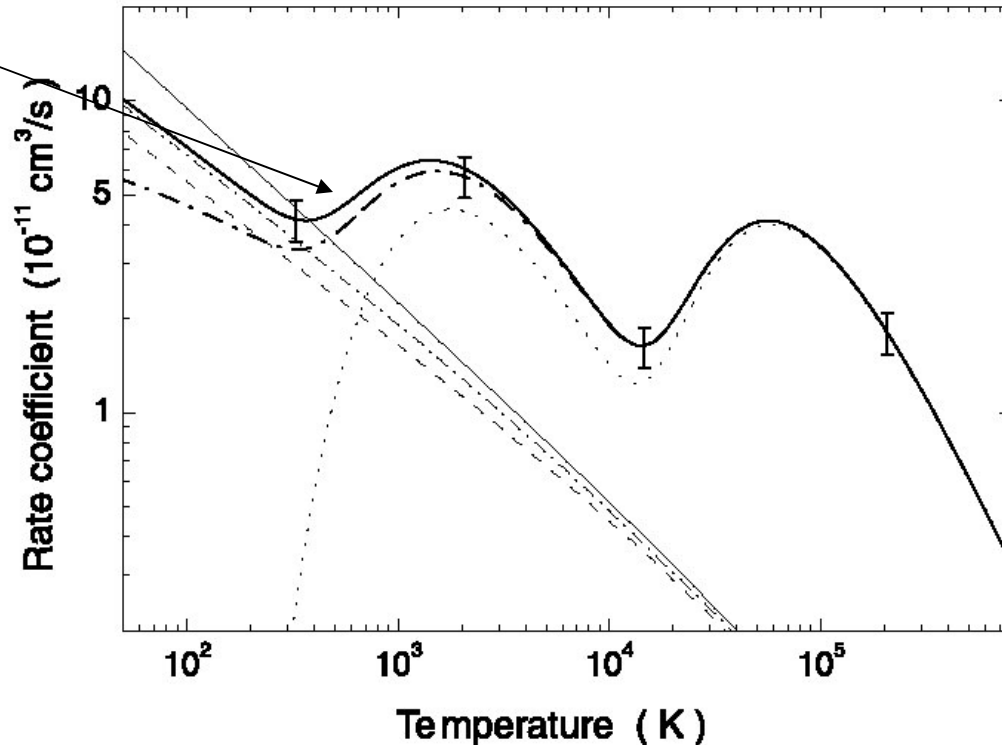
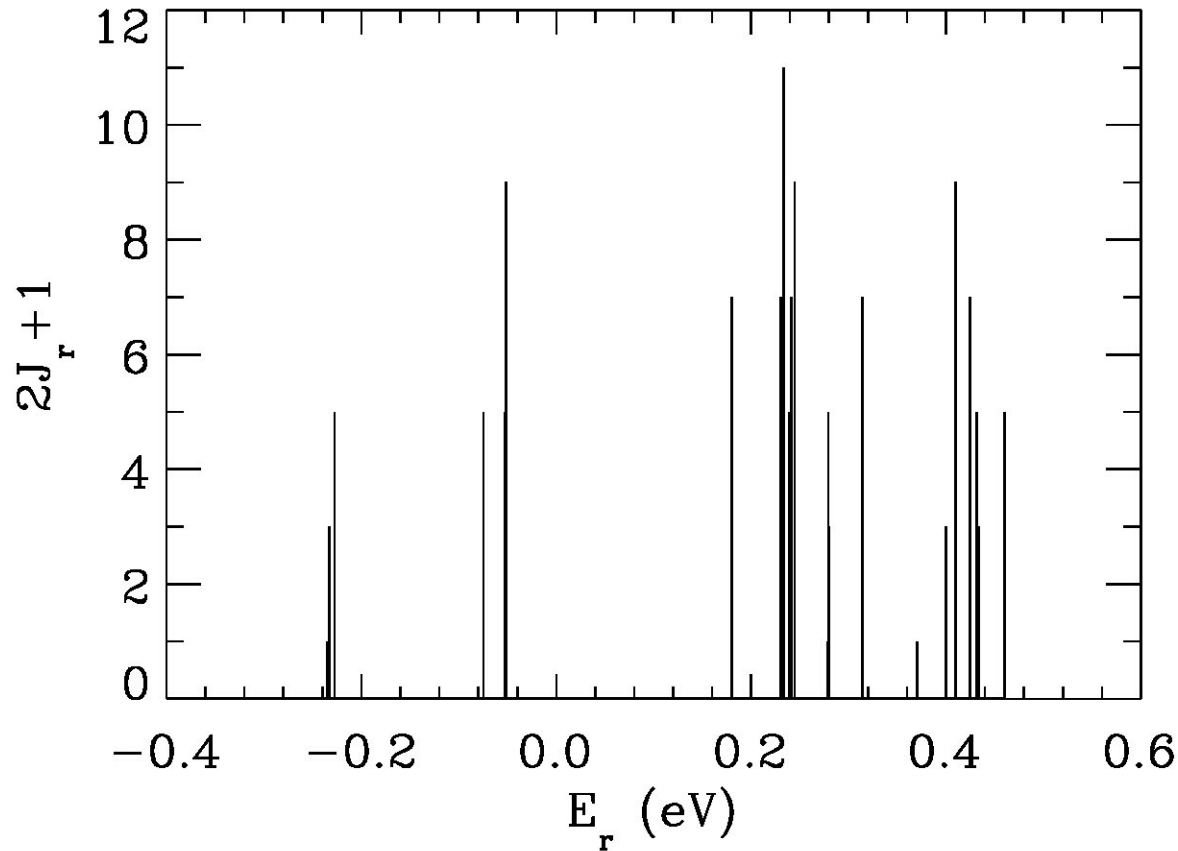


FIG. 8.—Experimental total C IV recombination rate coefficients in a plasma corrected for the influence of the finite experimental resolution (*thick solid line*; systematic error  $\pm 15\%$ ). The comparison with our pure DR rate coefficient (*dotted line*) shows that RR is noticeable up to  $\sim 30,000$  K. The thick dash-dotted line is our total recombination rate coefficient uncorrected for the influence of the finite experimental resolution. The other lines are C IV RR rate coefficients of Péquignot et al. (1991; *thin solid line*) and corresponding RR rate coefficients (see text) for  $n_{\max} = 20$  (*thin dashed line*) and  $n_{\max} = 40$  (*thin dash-dotted line*).

# All Near Threshold States

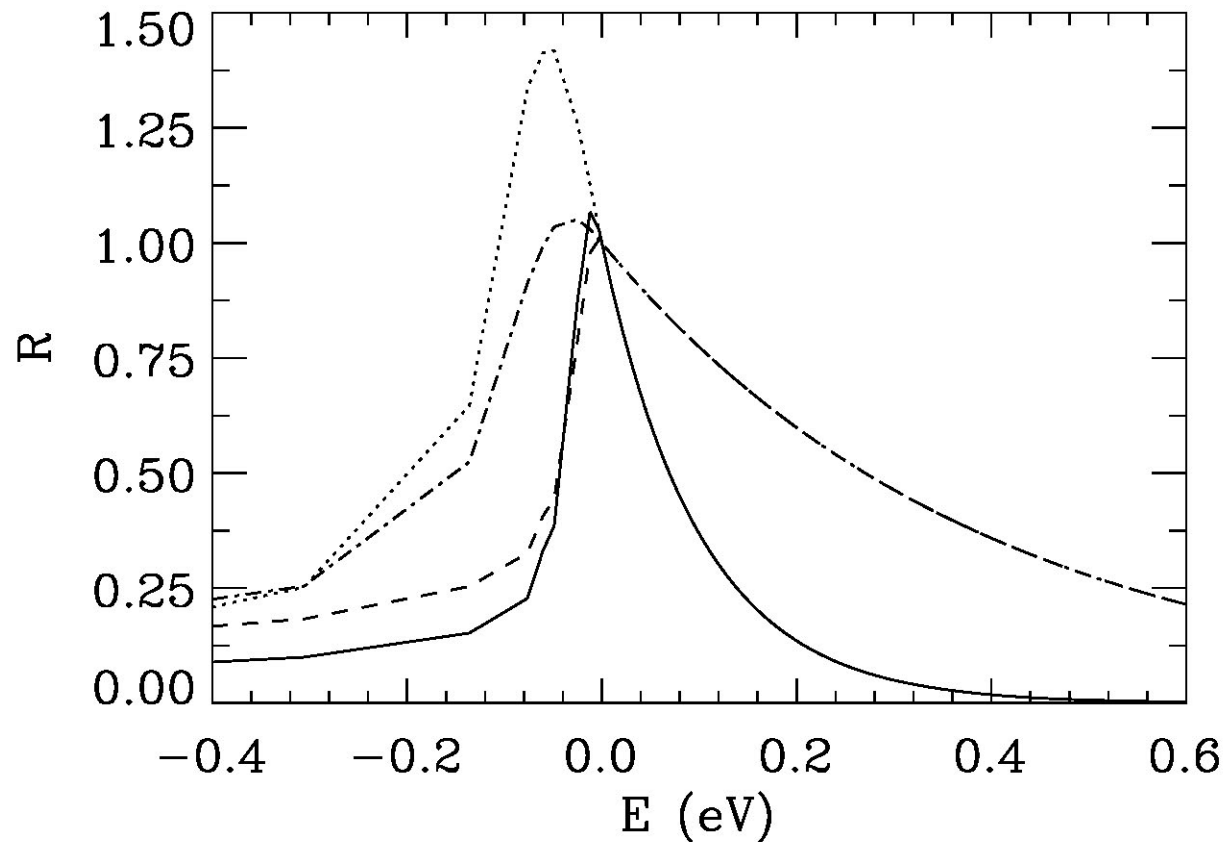


Energies &  
multiplicities  
from NIST  
database

Energies of all  $2p4L$  states within  $\frac{1}{2}$  eV of threshold

Why bother with negative energy states?

# Plasmas Populate Negative E



solid  $T = 0.1$  eV,  $2.2E6$   $cm^{-3}$ , dotted  $T = 0.1$  eV,  $2.2E8$   $cm^{-3}$   
dash  $T = 0.4$  eV,  $2.2E6$   $cm^{-3}$ , dot-dash  $T = 0.1$  eV,  $2.2E8$   $cm^{-3}$

# Negative E States “Autoionize”

PHYSICAL REVIEW A

VOLUME 15, NUMBER 1

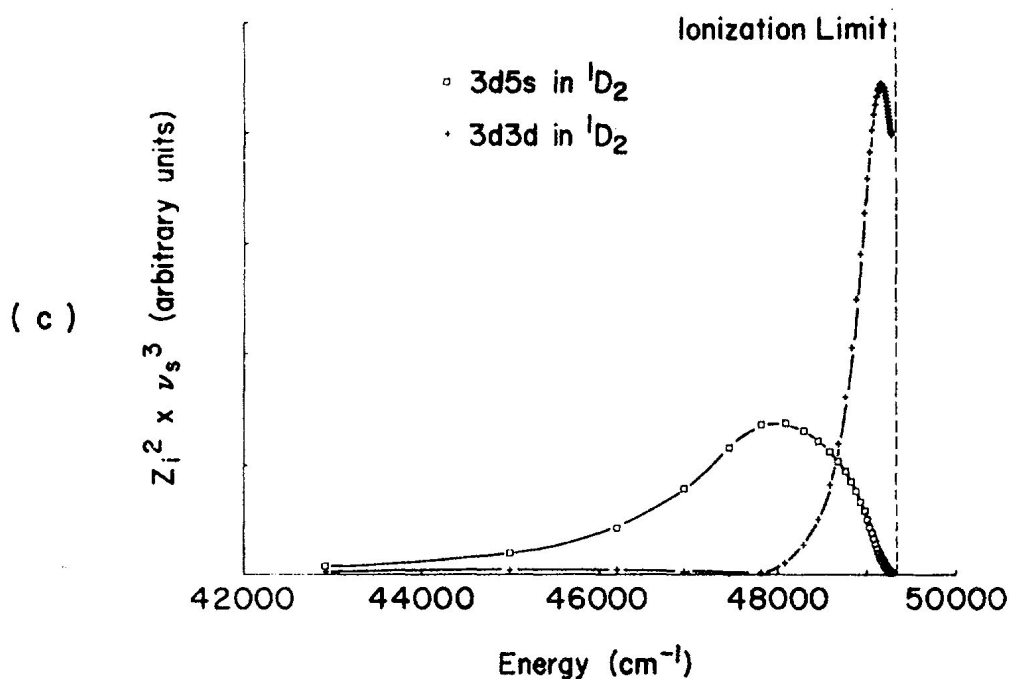
JANUARY 1977

## Bound even-parity $J = 0$ and 2 spectra of Ca: A multichannel quantum-defect theory analysis\*

J. A. Armstrong, P. Esherick, and J. J. Wynne

IBM Thomas J. Watson Research Center, Yorktown Heights, New York 10598

(Received 23 August 1976)



Mixture into  
the 4snd  
Rydberg  
series

# Number of Participating States

Compute thermal average of  $2 J_r + 1$

0.1 eV,  $2.2\text{E}6 \text{ cm}^{-3}$ :

Positive E: 7.2      Negative E: 11.6

0.1 eV,  $2.2\text{E}8 \text{ cm}^{-3}$ :

Positive E: 7.2      Negative E: 44

0.4 eV,  $2.2\text{E}6 \text{ cm}^{-3}$ :

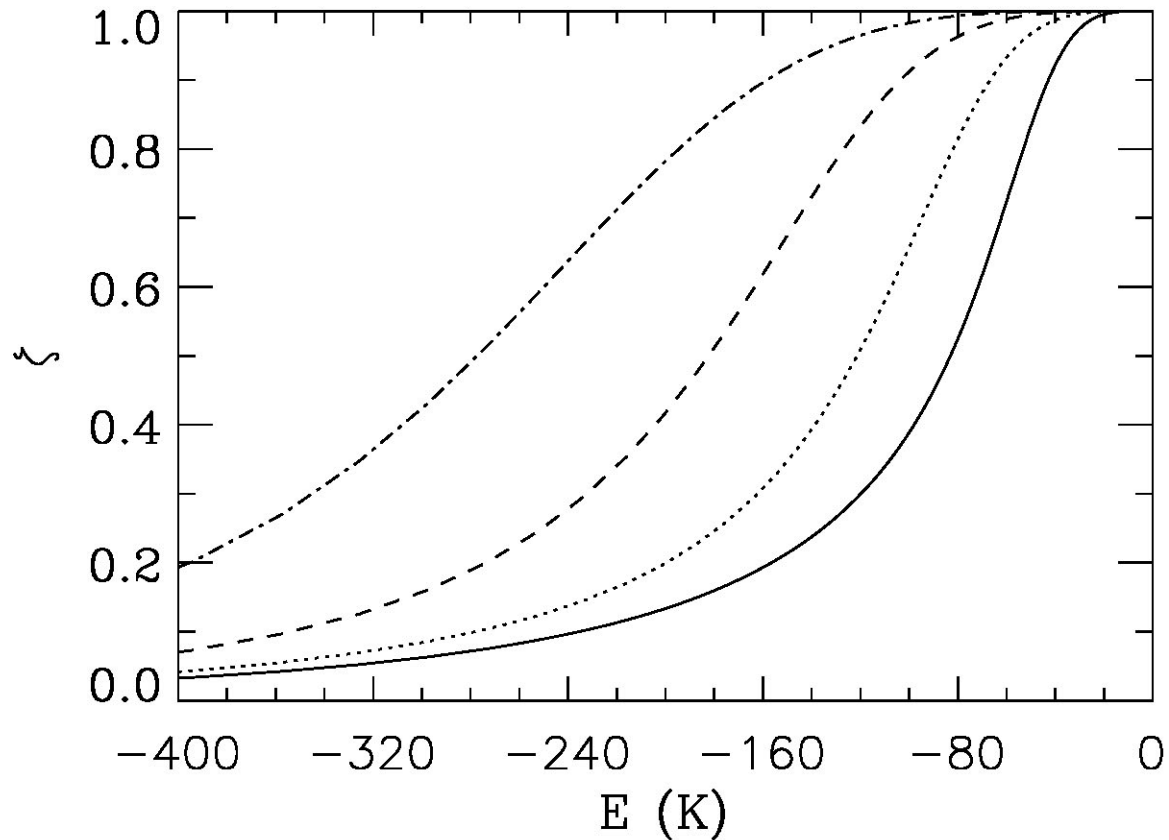
Positive E: 47      Negative E: 13.5

0.4 eV,  $2.2\text{E}8 \text{ cm}^{-3}$ :

Positive E: 47      Negative E: 32



# Ratio to Thermal @ 250 K



solid  $1.0E4 \text{ cm}^{-3}$ , dotted  $1.0E5 \text{ cm}^{-3}$

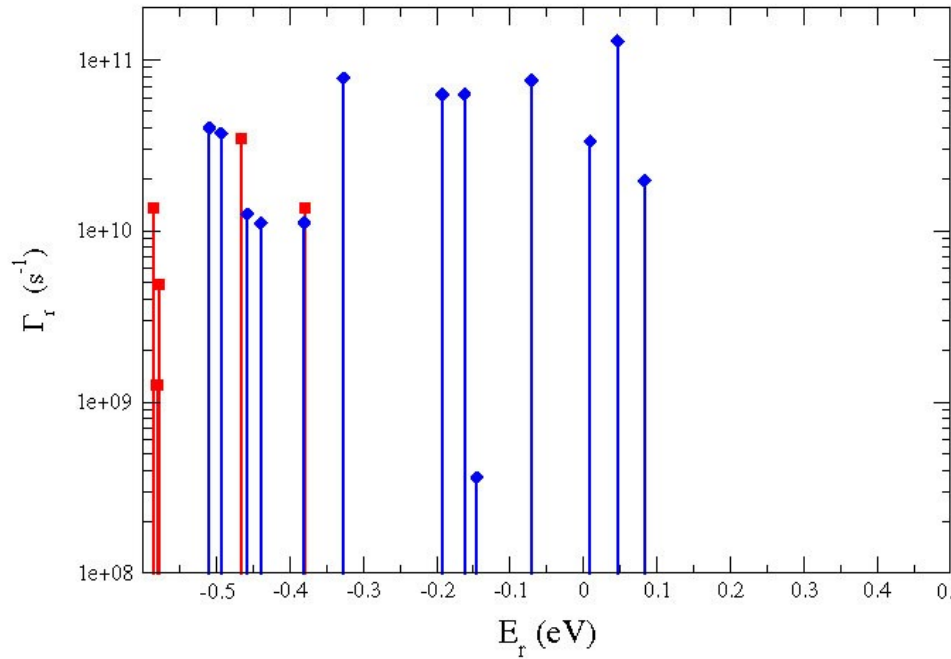
dash  $1.0E6 \text{ cm}^{-3}$ , dot-dash  $1.0E7 \text{ cm}^{-3}$

## Contribution of Near Threshold States to Recombination in Plasmas

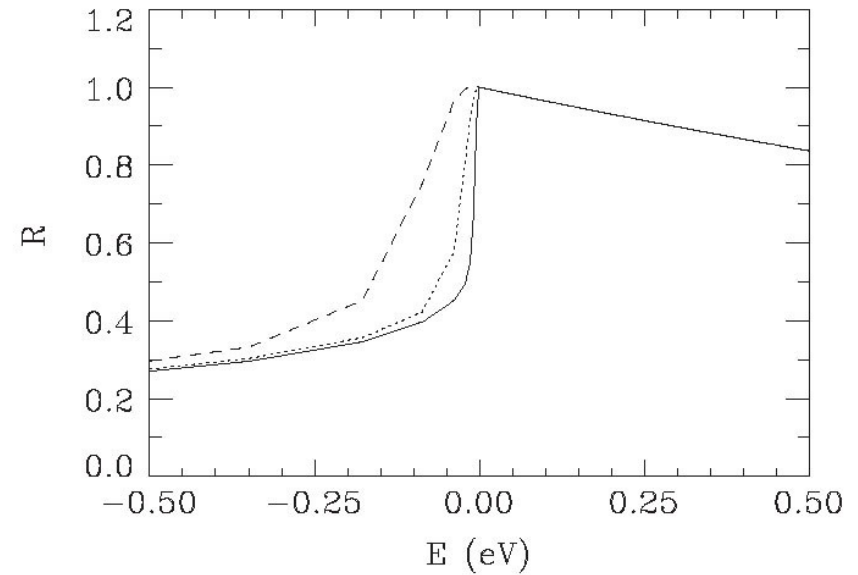
F. Robicheaux, S.D. Loch, M. S. Pindzola, and C.P. Ballance

*Department of Physics, Auburn University, Alabama 36849-5311, USA*

(Received 28 April 2010; published 30 November 2010)



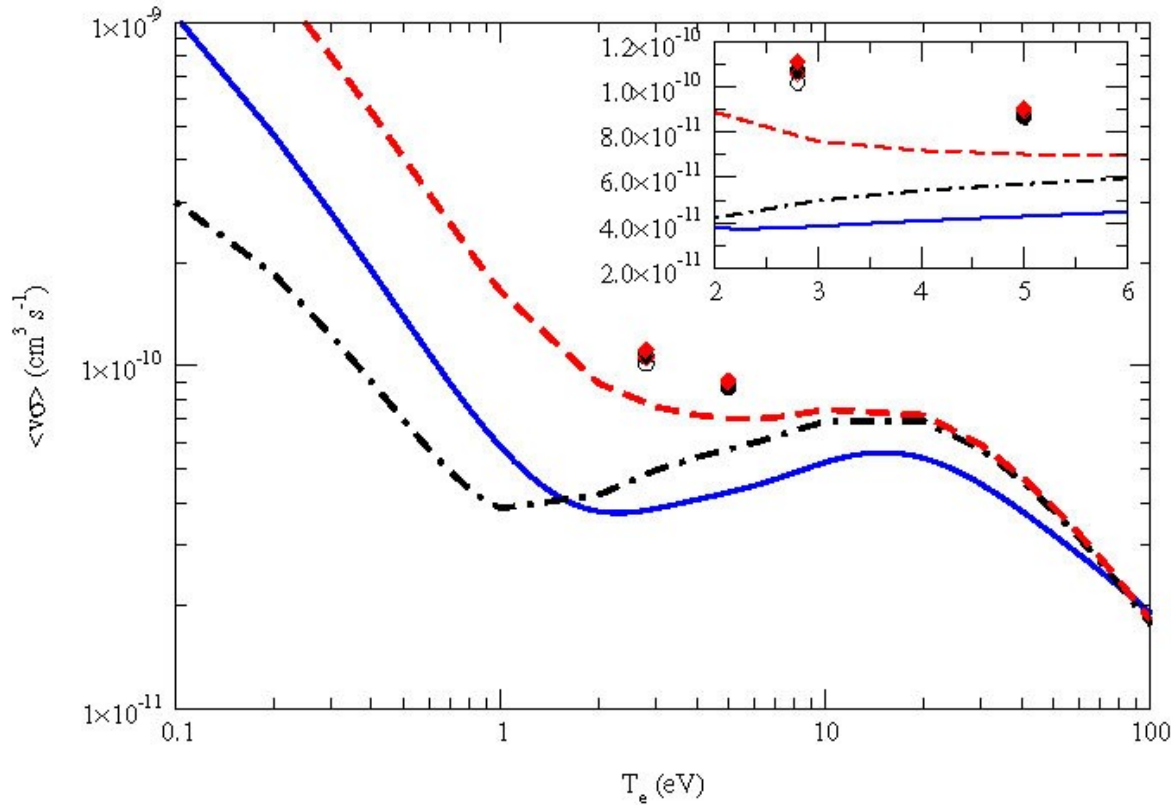
$\text{Mg}^{7+}$  states



$T = 2.8 \text{ eV}$

$10^4, 10^6, 10^8 \text{ cm}^{-3}$

# Contribution to Recombination Rate



Blue line = experiment, red line = correct Autostructure,  
black line = Autostructure (states below 70 meV shifted  
below threshold)

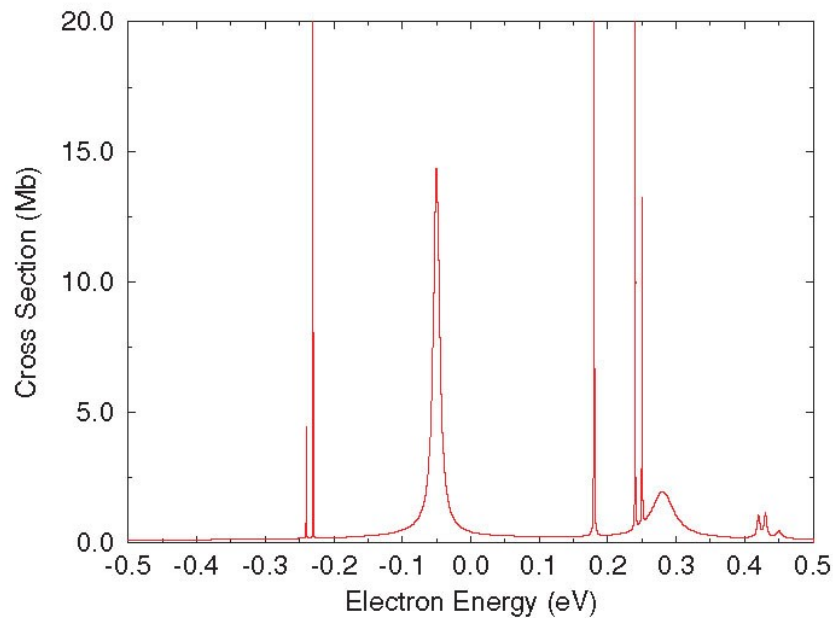
Symbols include negative E states (unshifted & shifted Auto)

# Dielectronic recombination in $C^{3+}$ above and below the ionization threshold

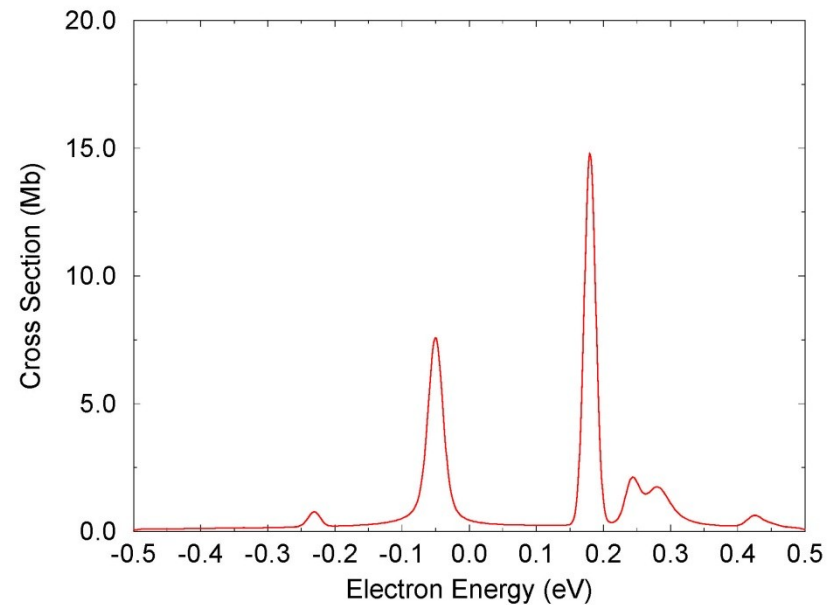
M. S. Pindzola, S. D. Loch, and F. Robicheaux

*Department of Physics, Auburn University, Auburn, Alabama, USA*

(Received 8 February 2011; published 8 April 2011)

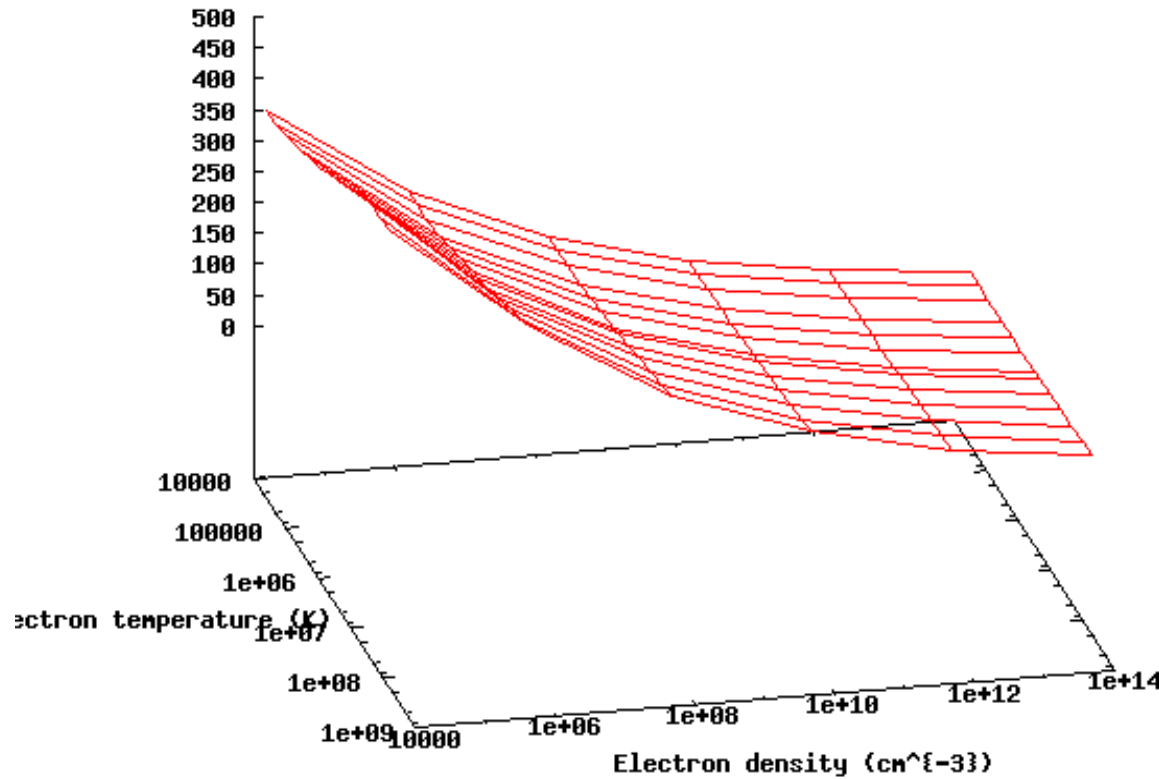


DR cross section



convolved 0.02 eV

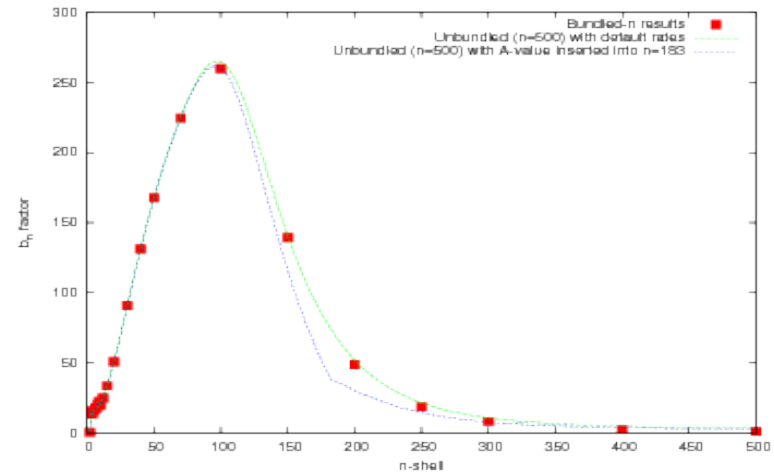
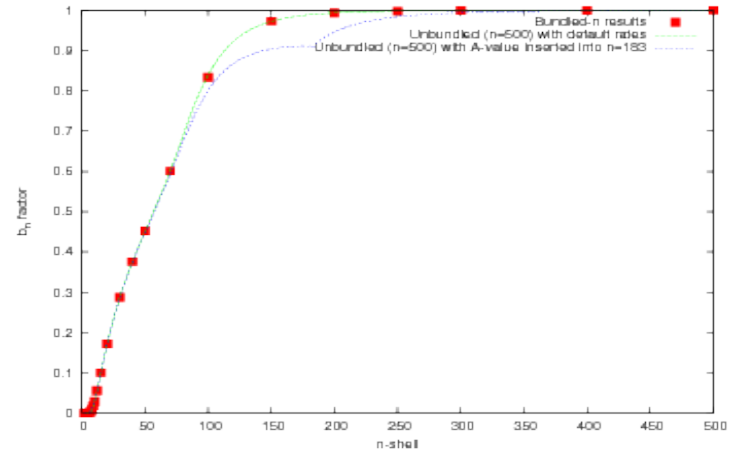
Ncrit for Mg<sup>7+</sup> ———



The plot shows the critical n-shell at which the Mg7+ Rydberg levels blend with their nearest neighbor.

# Population modeling of the Rydberg states

- We used ADAS204 to model the population of the 'negative energy' electrons.
  - Semi-empirical data for everything, except for DR (AUTOSTRUCTURE).
- We also investigated the role of allowing a doubly excited state embedded in the Rydberg 'continuum' to allow the Rydberg states to radiate.
- Results are shown for Mg7+ for  $T_e = 5.8 \times 10^4$  K (top plot) and  $4.47 \times 10^7$  K (bottom plot)



# Concluding Remarks

Perturber states just below threshold might contribute as much or more to low T processes

Compact states embedded in Rydberg series often left out

Simple theory if energy width is greater than Rydberg spacing (or big collisional width of Rydberg state)

Possible important processes: photo-recombination, electron impact excitation (weak transitions), dissociative recombination in molecular ions

Super accurate energy not necessarily important; energy error less than T